

TDA7454

PRODUCT PREVIEW

HIGH EFFICIENCY QUAD BRIDGE CAR RADIO POWER AMPLIFIER

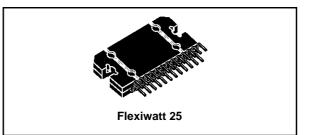
- HIGH OUTPUT POWER CAPABILITY 4 x 22W/4Ω @14.4V, 1KHz, 10%
- DUAL MODE OPERATING EXTERNALLY PRESETTABLE: CONVENTIONAL CLASS A-B MODE, HIGH EFFICIENCY MODE
- LOW EXTERNAL COMPONENTS COUNT: - NO BOOTSTRAP CAPACITORS - NO EXTERNAL COMPENSATION INTERNALLY FIXED GAIN (26dB)
- CLIPPING DETECTOR
- ST-BY FUNCTION (CMOS COMPATIBLE)
- MUTE FUNCTION (CMOS COMPATIBLE)
- AUTOMUTE AT MINIMUM SUPPLY **VOLTAGE DETECTION**
- LOW RADIATION

Protections:

- OUPUT SHORT CIRCUIT TO GND; TO Vs; ACROSS THE LOAD
- 3 STEPS OVERRATING CHIP TEMPERA-TURE
- LOAD DUMP VOLTAGE
- FORTUITOUS OPEN GND
- LOUDSPEAKER DC CURRENT
- ESD

BLOCK & APPLICATION DIAGRAM

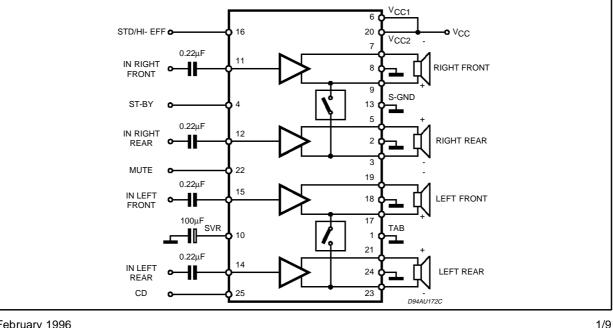
MULTIPOWER BCD TECHNOLOGY



DESCRIPTION

The TDA7454 is a new BCD technology QUAD BRIDGE type of car radio amplifier in Flexiwatt25 package specially intended for car radio applications.

Among the features, its superior efficiency performance coming from the internal exclusive structure, makes it the most suitable device to simplify the thermal management in high power sets. The dissipated output power under average listening condition is in fact reduced up to 50% when compared to the level provided by conventional class AB solutions.



February 1996

This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

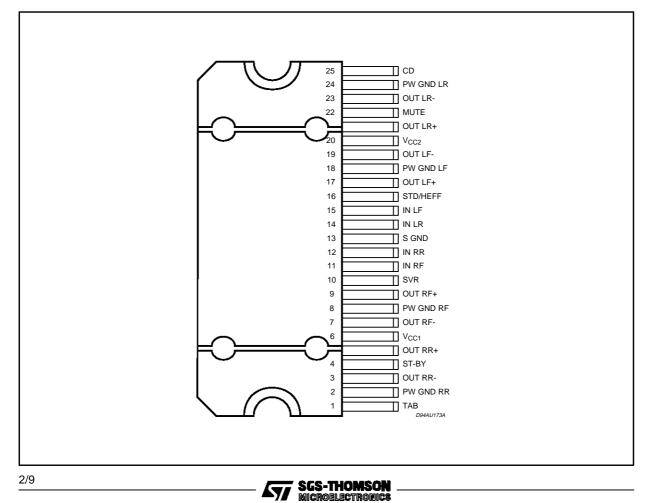
ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-----------------------------------|--|------------|------|
| V _{op} | Operating Supply Voltage | 18 | V |
| Vs | DC Supply Voltage | 28 | V |
| V _{peak} | Peak Supply Voltage (for t = 50ms) | 40 | V |
| lo | Output Peak Current (not repetitive t = 100µs) | 4.5 | А |
| lo | Output Peak Current (repetitive f > 10Hz) | 3.5 | А |
| P _{tot} | Power Dissipation T _{case} = 70°C | 86 | W |
| T _{stg} , T _j | Storage and Junction Temperature | -55 to 150 | °C |

THERMAL DATA

| Symbol | Description | | | Unit |
|------------------------|----------------------------------|--|---|------|
| R _{th j-case} | Thermal Resistance Junction-case | | 1 | °C/W |

PIN CONNECTION (Top view)



| ELECTRICAL CHARACTERISTICS (Refer to the test circuit $V_S = 14.4V$; $R_L = 4\Omega$; $f = 1KHz$; |
|---|
| T _{amb} = 25°C, unless otherwise specified |

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Unit |
|---------------------|---|--|------|--------------|------|----------|
| Vs | Supply Voltage Range | | 8 | | 18 | V |
| l _d | Total Quiescent Drain Current | | | 140 | | mA |
| Po | Output Power | @ EIAJ | | 30 | | W |
| | | THD = 10% | | 22 | | W |
| | | THD = 1% : BTL MODE | | 18 | | W |
| THD | Total harmonic distortion | $P_O = 1W$: BTL MODE $P_O = 10W$: BTL MODE | | 0.03 0.03 | | % % |
| | | $P_O = 1W$: Hi-EFF MODE $P_O = 10W$: Hi-EFF MODE | | 0.03 0.3 | | % % |
| Ст | Cross Talk | f = 1KHz f = 10KHz | | 55 45 | | dB dB |
| R _{IN} | Input Impedance | | | 15 | | KΩ |
| Gv | Voltage Gain | | 25 | 26 | 27 | dB |
| ΔGv | Voltage Gain Match | | | | 1 | dB |
| E _{IN} | Output Noise Voltage | $R_g = 600\Omega$ | | 100 | | mV |
| SVR | Supply Voltage Rejection | $ f = 300Hz; Vr = 1Vpp; \\ R_g = 0 \text{ to } 100\Omega; $ | | 50 | | dB |
| BW | Power Bandwidth | (–3dB) | 75 | | | KHz |
| A _{SB} | Stand-by Attenuation | | | 100 | | dB |
| V _{sb IN} | Stand-by in Threshold | | | | 1.5 | V |
| V _{sb OUT} | Stand-by out Threshold | | 3.5 | | | V |
| I _{sb} | Stand-by Current Consumption | | | | 100 | μA |
| A _M | Mute Attenuation | | | 90 | | dB |
| V _{M IN} | Mute in Thereshold | | | | 1.5 | V |
| V _{M OUT} | Mute out Threshold | | 3.5 | | | V |
| I _M | Mute pin Current (Sourced) | | | 1 | | μA |
| | Mode Select Switch | Standard BTL Mode Op. (Vpin16) | | Open | | |
| | | High Efficiency Mode (V _{pin 16}) | | | 0.5 | V |
| CD | Clip Det. out Current (Pull up to 5V with $10K\Omega$) | CD off: P _{Omin} = 10W CD on: THD = 5% | | 150 | 5 | μΑ μΑ |



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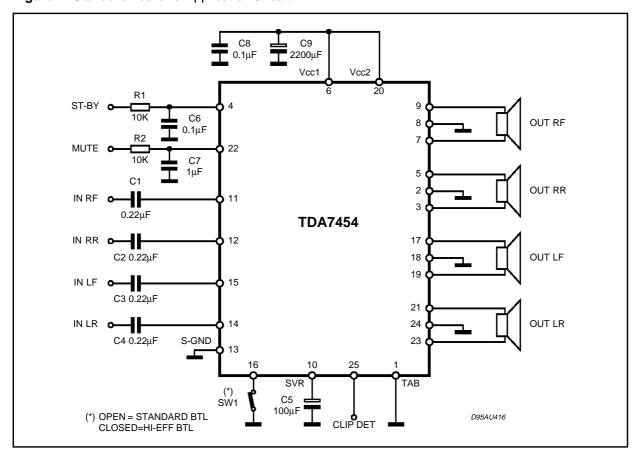


Figure 1: Standard Test and Application Circuit.



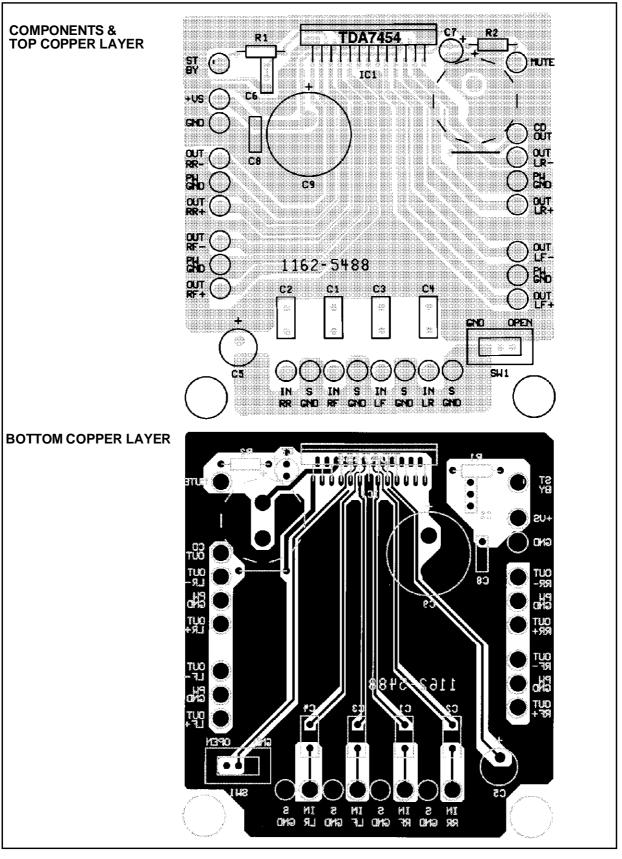


Figure 2: P.C.B. and components layout of fig. 1 circuit. (1.25:1 scale)



MODE SELECTION TABLE OPERATION OF THE DEVICE

| 1) STD/HI-EFF (pin 16 = | OPEN) | | | | |
|---|------------------------------|------------------------------------|------------|-------------------|--|
| STANDARD QUAD BRIDGE MODE | HIGH-EFF QUAD BRIDGE MODE | STANDARD QUAD SINGLE-ENDED MODE | ST-BY MODE | - Tchip (deg) | |
| 1 | 00 1 | 50 1 [°] | 70 | | |
| 2) STD/HI-EFF (pin 16 = | GND) | | | | |
| HIGH-EFF QUAL | D BRIDGE MODE | STANDARD QUAD SINGLE-ENDED MODE | ST-BY MODE | - ►Tchip (deg) | |
| | 1 | 50 1 [°] | 70 | 1 (0) | |
| 1) STD/HI-EFF (pin 16 co | onnected as shown in the | figure below. | 1 | _ | |
| STANDARD QUAD BRIDGE MODE OR HIGH-EFF MODE (Theatsink dependent) | HIGH-EFF QUAD BRIDGE MODE | STANDARD QUAD SINGLE-ENDED MODE | ST-BY MODE | Tchip (deg) | |
| 1 | 00 1 | 50 1 [.] | 70 | | |
| STD/HI-EFF (pin 16) | | | | | |

Figure 3: Quiescent Current vs. Supply Voltage

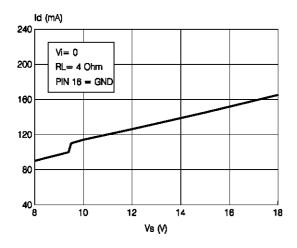


Figure 4: Output Power vs. Supply Voltage

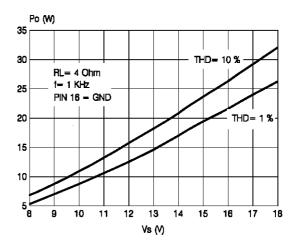




Figure 5: Distortion vs. Frequency

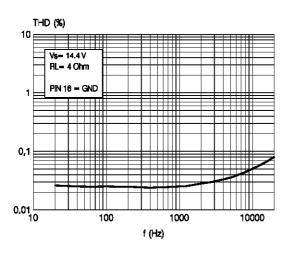


Figure 7: Supply Voltage Rejection vs. Frequency

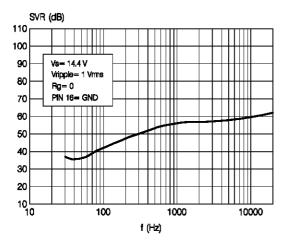
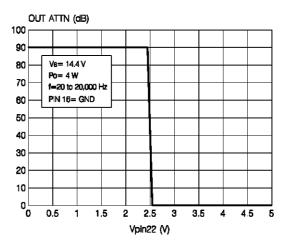
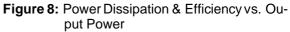
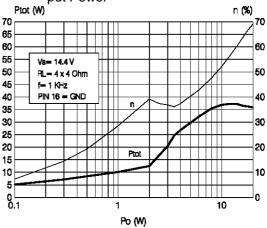


Figure 6: Muting Attenuation vs. Vpin 22





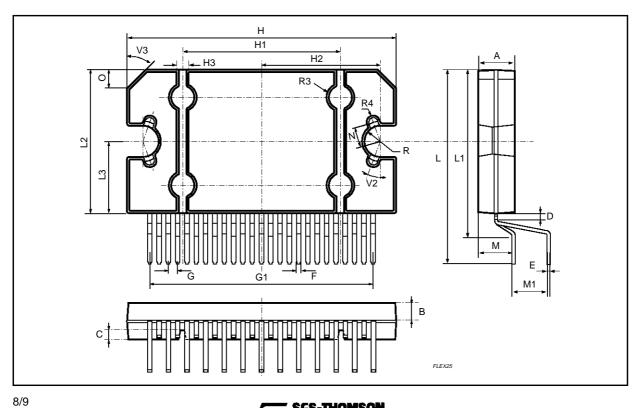




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| DIM. | mm | | | inch | | | |
|------|-------|-------|-------|-------|-------|-------|--|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. | |
| А | 4.45 | | 4.65 | 0.175 | | 0.183 | |
| В | 1.80 | 1.90 | 2.00 | 0.070 | 0.074 | 0.079 | |
| С | | 1.40 | | | 0.055 | | |
| D | 0.75 | 0.90 | 1.05 | 0.029 | 0.035 | 0.041 | |
| E | 0.37 | 0.39 | 0.42 | 0.014 | 0.015 | 0.016 | |
| F | | | 0.57 | | | 0.022 | |
| G | 0.80 | 1.00 | 1.20 | 0.031 | 0.040 | 0.047 | |
| G1 | 23.75 | 24.00 | 24.25 | 0.935 | 0.945 | 0.955 | |
| Н | 28.90 | 29.23 | 29.30 | 1.138 | 1.150 | 1.153 | |
| H1 | | 17.00 | | | 0.669 | | |
| H2 | | 12.80 | | | 0.503 | | |
| H3 | | 0.80 | | | 0.031 | | |
| L | 21.57 | 21.97 | 22.37 | 0.849 | 0.865 | 0.880 | |
| L1 | 18.57 | 18.97 | 19.37 | 0.731 | 0.786 | 0.762 | |
| L2 | 15.50 | 15.70 | 15.90 | 0.610 | 0.618 | 0.626 | |
| L3 | 7.70 | 7.85 | 7.95 | 0.303 | 0.309 | 0.313 | |
| М | 3.70 | 4.00 | 4.30 | 0.145 | 0.157 | 0.169 | |
| M1 | 3.60 | 4.00 | 4.40 | 0.142 | 0.157 | 0.173 | |
| Ν | | 2.20 | | | 0.086 | | |
| 0 | | 2 | | | 0.079 | | |
| R | | 1.70 | | | 0.067 | | |
| R4 | | 0.50 | | | 0.019 | | |
| V2 | 20° | | | | | | |
| V3 | 45° | | | | | | |

FLEXIWATT25 PACKAGE MECHANICAL DATA



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